NSN 5962-01-175-8584

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches	and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Dise	ipation Rating:
794.0 milliwatts	
Operating Tempuratu	re Range:
-0.0/+75.0 degrees ce	lsius
Storage Tempurature	Range:
65.0/+150.0 degrees	celsius
Features Provided:	
Hermetically sealed ar	d burn in and programmable and bipolar and 3-state output
nclosure Material:	
Ceramic	
nclosure Configurat	on:
Dual-in-line	
Output Logic Form:	
Fransistor-transistor lo	gic
nput Circuit Pattern:	
0 input	
ase Outline Source	And Designator:
)-2 mil-m-38510	
Ferminal Surface Tre	atment:
Solder	
Voltage Rating And T	ype Per Characteristic:
0.5 volts power sourc	e and 7.0 volts power source
Time Rating Per Cha	steristic:
35.00 nanoseconds p	opagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type	
Prom	
Memory Capacity:	
Unknown	
Terminal Type And Q	uantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	

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